

# 2MBI1000XRNE120-50

IGBT Modules

**Power Module (X series)**  
**1200V / 1000A / 2-in-1 package**

■ **Features**

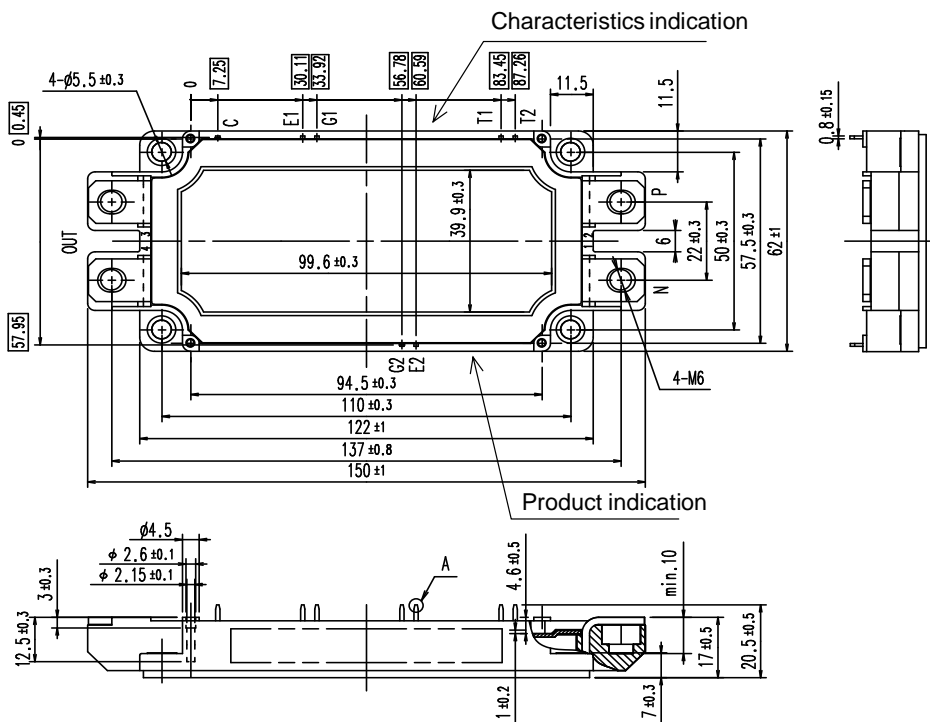
- LOW  $V_{CE(sat)}$
- Low Inductance Module structure
- Solder pin terminals

■ **Applications**

- Inverter for Motor Drives, AC and DC Servo Drives
- Uninterruptible Power Supply Systems, Wind Turbines, PV Power Conditioning Systems



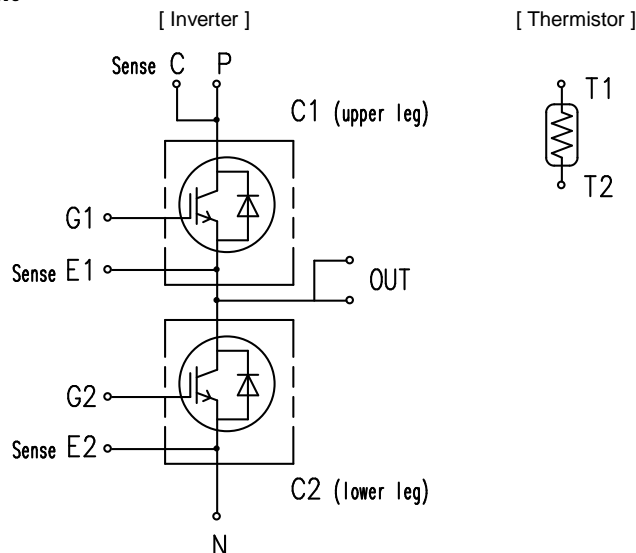
■ **Outline drawing ( Unit : mm )**



NOTE)   shows theoretical dimension and tolerance is  $\phi \pm 0.5$

Weight: 350 g(typ.)

■ **Equivalent Circuit**



# 2MBI1000XRNE120-50

**■ Absolute Maximum Ratings (at  $T_c=25^\circ\text{C}$  unless otherwise specified)**

Items		Symbols	Conditions	Maximum Ratings	Units
Inverter	Collector-Emitter voltage, Gate-Emitter short-circuited	$V_{CES}$		1200	V
	Gate-Emitter voltage, Collector-Emitter short-circuited	$V_{GES}$		$\pm 20$	V
	Collector current	$I_C$	Continuous   $T_c=100^\circ\text{C}$	1000	A
	Repetitive peak collector current	$I_{CRM}$	1ms	2000	
	Reverse-conducting current	$I_{RC}$	Continuous	1000	
	Repetitive peak reverse-conducting current	$I_{RCRM}$	1ms	2000	
	Total power dissipation	$P_{tot}$	1 device	8330	W
	Virtual junction temperature	$T_{vj}$		175	°C
	Operating virtual junction temperature (under switching conditions)	$T_{vjop}$		175	
	Case temperature	$T_c$		150	
Storage temperature	$T_{stg}$		-40 ~ 150		
Isolation voltage	between terminal and copper base (*1) between thermistor and others (*2)	$V_{isol}$	AC: 1min.	4000	Vrms
Mounting torque for screws to heatsink (*3)		$M_s$	M5	6.0	N·m
Mounting torque for terminal screws (*3)		$M_t$	M6	6.0	

(\*1) All terminals should be connected together during the test.

(\*2) Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

(\*3) Recommendable Value: Mounting                      2.5 ~ 6.0 N·m (M5)  
Recommendable Value: Terminals                        3.5 ~ 6.0 N·m (M6)

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**IGBT Modules**
**■ Electrical characteristics (at  $T_{vj}= 25^{\circ}\text{C}$  unless otherwise specified)**

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Collector-Emitter cut-off current, Gate-Emitter short-circuited	$I_{CES}$	$V_{GE} = 0V$ $V_{CE} = 1200V$	-	-	200	$\mu\text{A}$	
Gate leakage current, Collector-Emitter short-circuited	$I_{GES}$	$V_{CE}=0V, V_{GE}=\pm 20V$	-	-	400	nA	
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20V$ $I_C = 1000\text{mA}$	5.75	6.40	7.00	V	
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_C = 1000A$	$T_{vj}=25^{\circ}\text{C}$	-	2.80	3.35	V
			$T_{vj}=25^{\circ}\text{C}$	-	1.60	2.05	
	$T_{vj}=125^{\circ}\text{C}$		-	1.90	-		
	$T_{vj}=150^{\circ}\text{C}$		-	2.00	-		
	$T_{vj}=175^{\circ}\text{C}$		-	2.05	-		
Internal gate resistance	$r_g$	-	-	0.95	-	$\Omega$	
			-	126	-	nF	
Input capacitance	$C_{ies}$	$V_{CE}=10V, V_{GE}=0V, f=1\text{MHz}$	-	5.3	-		
Output capacitance	$C_{oes}$		-	1.19	-		
Reverse transfer capacitance	$C_{res}$		-	-	-		
Gate charge	$Q_G$	$V_{CC} = 600V, I_C = 1000A$ $V_{GE} = -15 \rightarrow +15V$	-	7.8	-	$\mu\text{C}$	
Reverse-conducting voltage	$V_{RC}$ (terminal)	$V_{GE} = 0V$ $I_{RC} = 1000A$	$T_{vj}=25^{\circ}\text{C}$	-	2.90	3.45	V
			$T_{vj}=25^{\circ}\text{C}$	-	1.70	2.15	
	$T_{vj}=125^{\circ}\text{C}$		-	1.90	-		
	$T_{vj}=150^{\circ}\text{C}$		-	1.90	-		
	$T_{vj}=175^{\circ}\text{C}$		-	1.90	-		
Turn-on delay time(*1)	$t_{d(on)}$	$V_{CC} = 600V$ $I_C, I_{RC} = 1000A$ $V_{GE} = \pm 15V$ $R_G = 0.5\Omega$ $L_S = 35\text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.36	-	$\mu\text{s}$
			$T_{vj}=125^{\circ}\text{C}$	-	0.40	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.42	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.43	-	
Rise time	$t_r$		$T_{vj}=25^{\circ}\text{C}$	-	0.10	-	
			$T_{vj}=125^{\circ}\text{C}$	-	0.11	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.11	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.12	-	
Turn-off delay time(*2)	$t_{d(off)}$		$T_{vj}=25^{\circ}\text{C}$	-	0.50	-	
			$T_{vj}=125^{\circ}\text{C}$	-	0.53	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.53	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.54	-	
Fall time	$t_f$	$T_{vj}=25^{\circ}\text{C}$	-	0.09	-		
		$T_{vj}=125^{\circ}\text{C}$	-	0.13	-		
		$T_{vj}=150^{\circ}\text{C}$	-	0.14	-		
		$T_{vj}=175^{\circ}\text{C}$	-	0.15	-		
Forward recovery time	$t_{fr}$	$T_{vj}=25^{\circ}\text{C}$	-	0.30	-		
		$T_{vj}=125^{\circ}\text{C}$	-	0.38	-		
		$T_{vj}=150^{\circ}\text{C}$	-	0.40	-		
		$T_{vj}=175^{\circ}\text{C}$	-	0.45	-		

 (\*1) Turn on time ( $t_{on}$ ) =  $t_{d(on)} + t_r$ 

 (\*2) Turn off time ( $t_{off}$ ) =  $t_{d(off)} +$

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IGBT Modules

■ Electrical characteristics (at  $T_{vj}=25^{\circ}\text{C}$  unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units		
			min.	typ.	max.			
Inverter	Turn-on energy (per puls)	$V_{CC} = 600\text{V}$ $I_C, I_{RC} = 1000\text{A}$ $V_{GE} = \pm 15\text{V}$ $R_G = 0.5\Omega$ $L_S = 35\text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	60.6	-	mJ	
			$T_{vj}=125^{\circ}\text{C}$	-	85.2	-		
			$T_{vj}=150^{\circ}\text{C}$	-	91.0	-		
			$T_{vj}=175^{\circ}\text{C}$	-	97.3	-		
	Turn-off energy (per puls)		$E_{off}$	$T_{vj}=25^{\circ}\text{C}$	-	93.9		-
				$T_{vj}=125^{\circ}\text{C}$	-	116.0		-
				$T_{vj}=150^{\circ}\text{C}$	-	120.5		-
	Forward recovery energy (per puls)		$E_{fr}$	$T_{vj}=175^{\circ}\text{C}$	-	124.8		-
				$T_{vj}=25^{\circ}\text{C}$	-	46.0		-
$T_{vj}=125^{\circ}\text{C}$		-		72.8	-			
Thermistor	Resistance	$R$	$T = 25^{\circ}\text{C}$	-	5000	-	$\Omega$	
			$T = 100^{\circ}\text{C}$	465	495	520		
	B value	$B$	$T = 25/50^{\circ}\text{C}$		3305	3375	3450	K

NOTICE:

The external gate resistance ( $R_G$ ) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum  $R_G$  depends on circuit configuration and/or environment. We recommend that the  $R_G$  has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

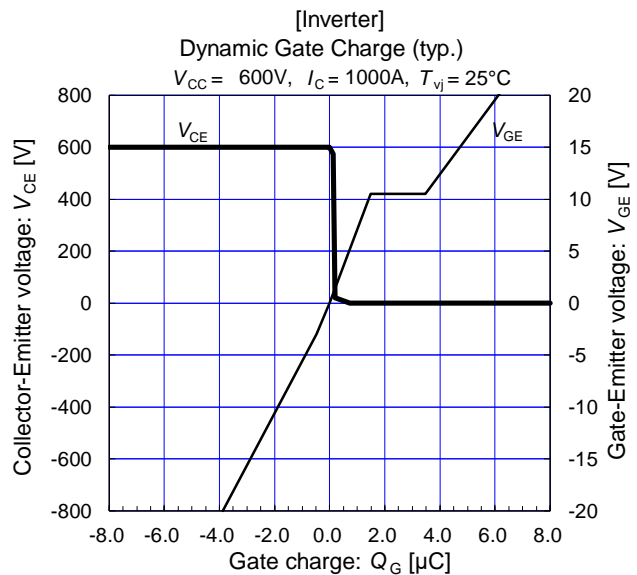
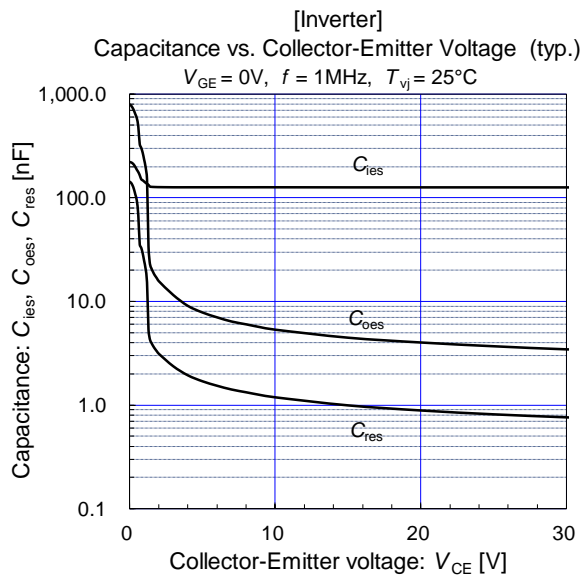
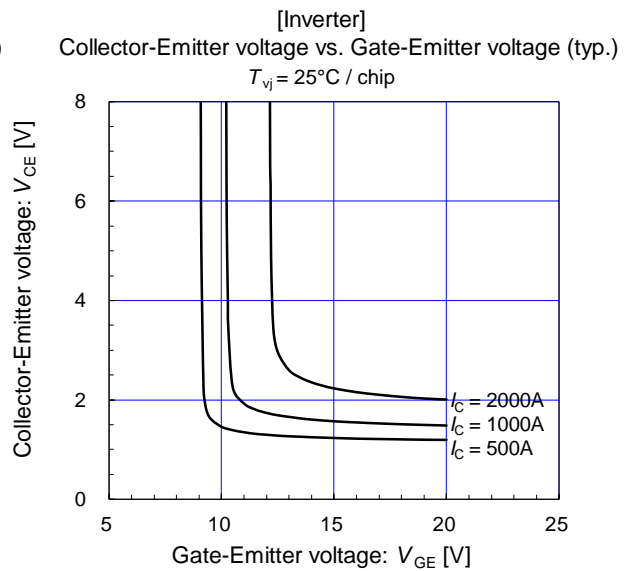
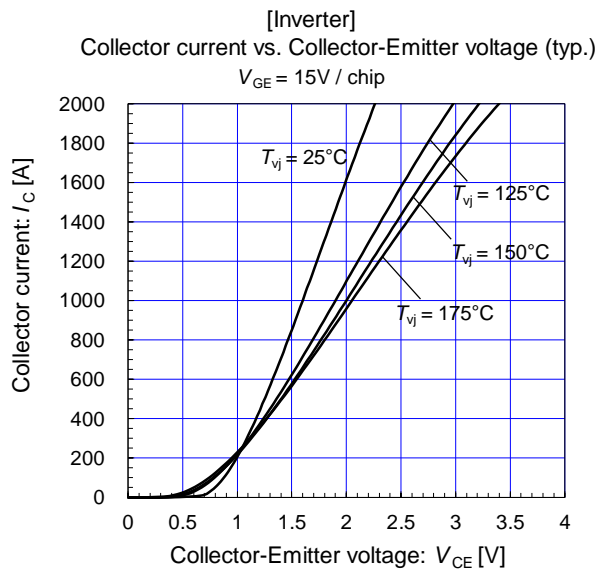
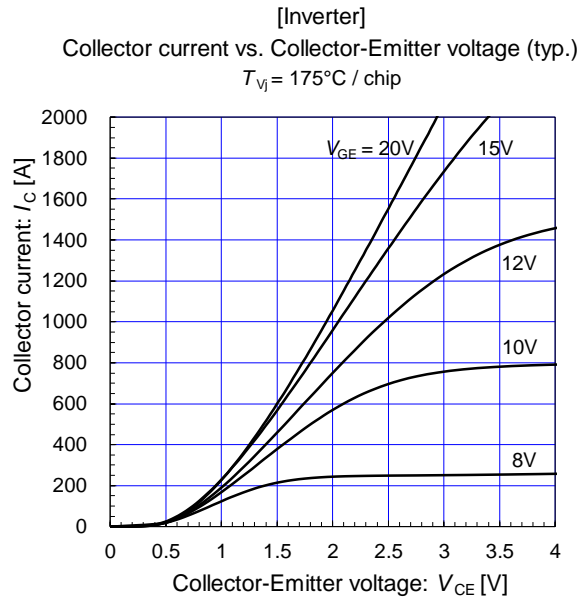
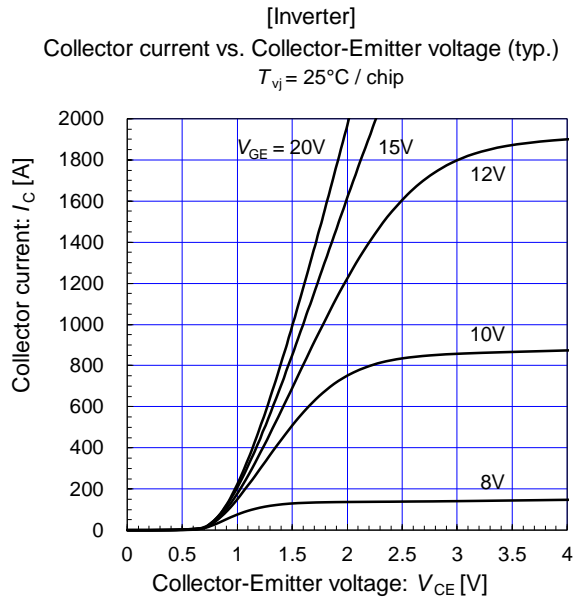
■ Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance junction to case(1 device)	$R_{th(j-c)}$	Inverter RC-IGBT	-	-	0.018	K/W
Thermal resistance case to heatsink(1 IGBT+1 FWD)(*1)	$R_{th(c-s)}$	with 1 W/(m·K) thermal grease	-	0.02	-	

(\*1) This is the value which is defined mounting on the additional cooling fin with thermal grease.

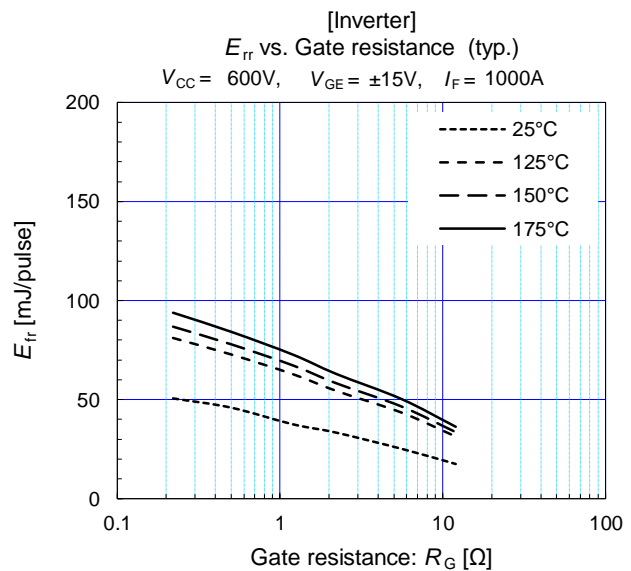
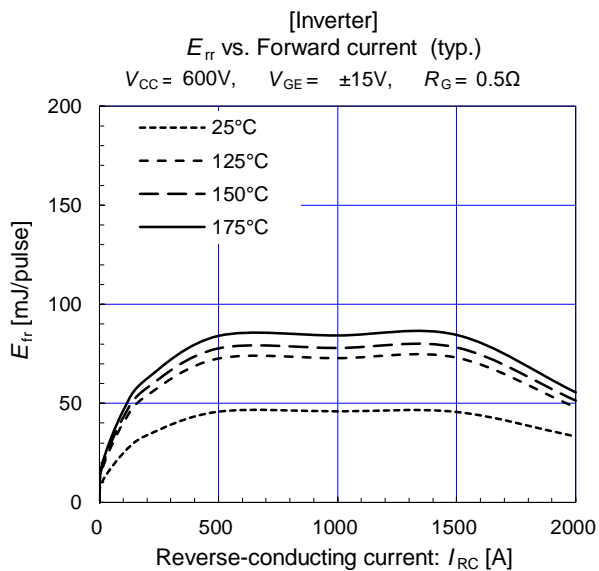
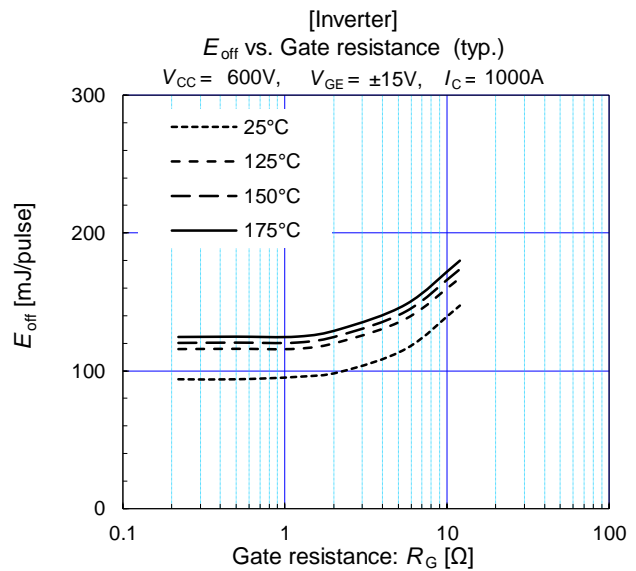
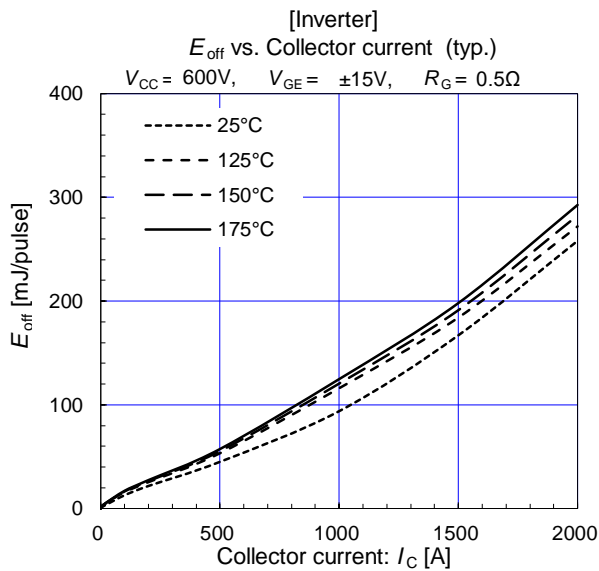
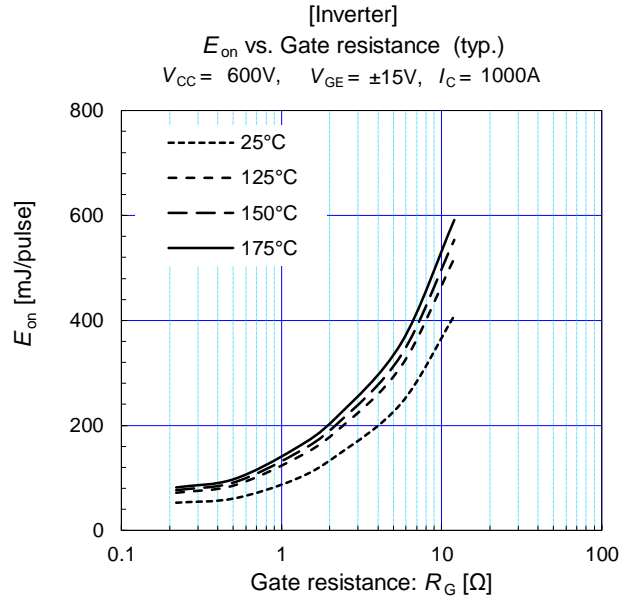
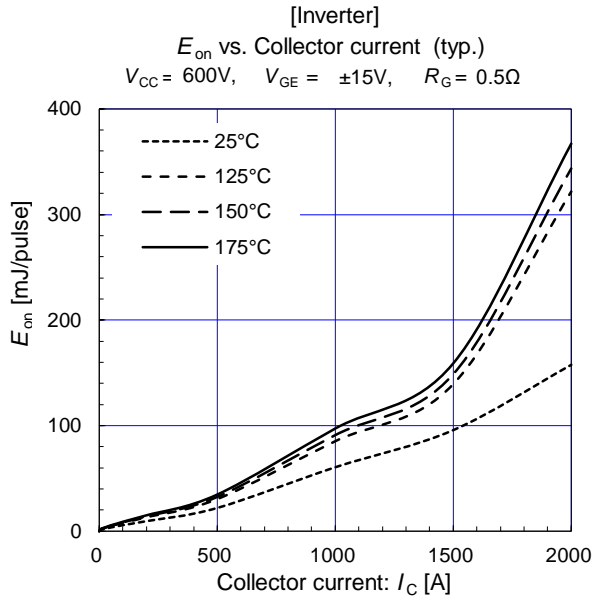
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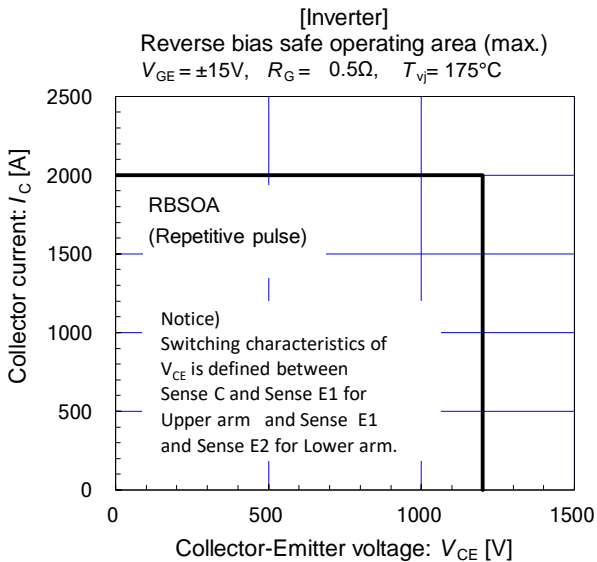
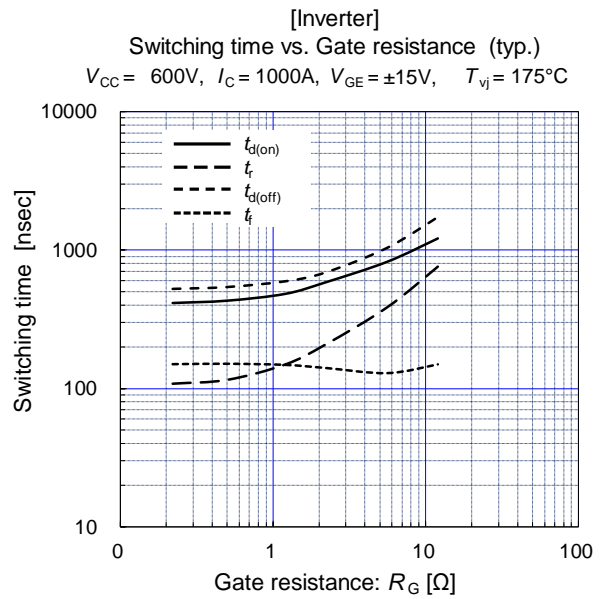
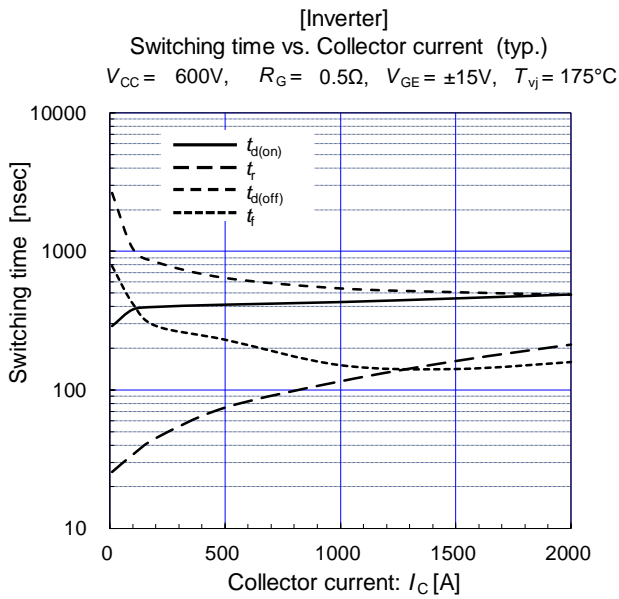
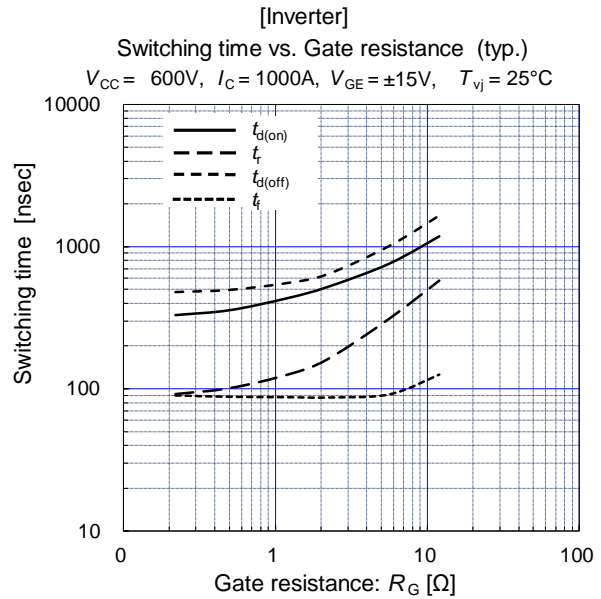
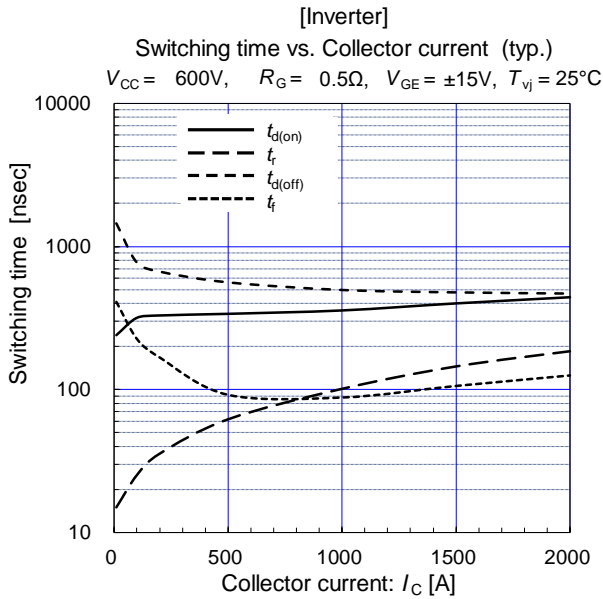
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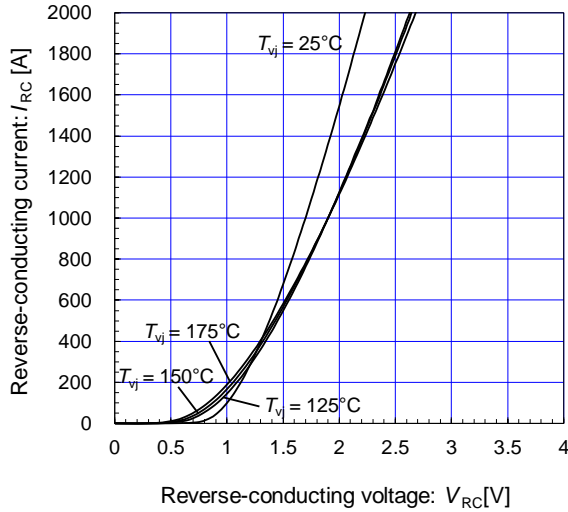
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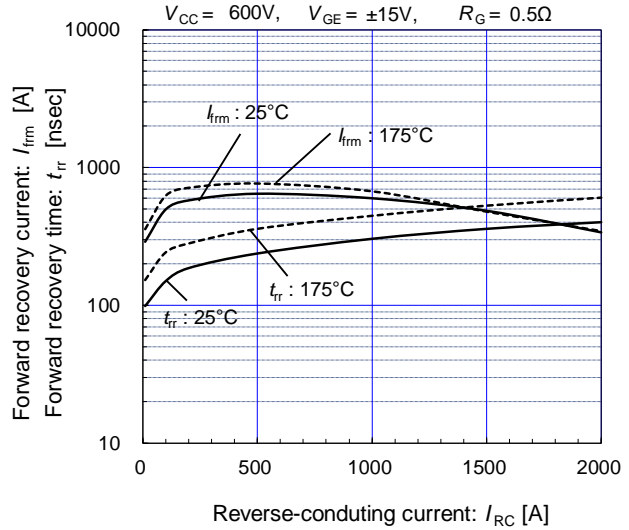
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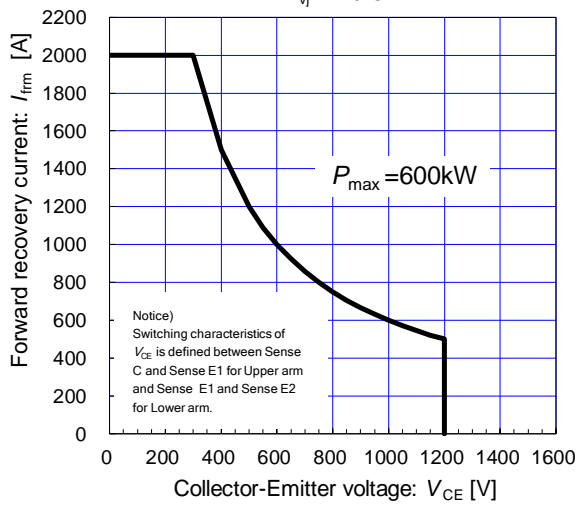
[Inverter]  
Reverse-conducting current vs. Reverse-conducting voltage  
(typ.) chip



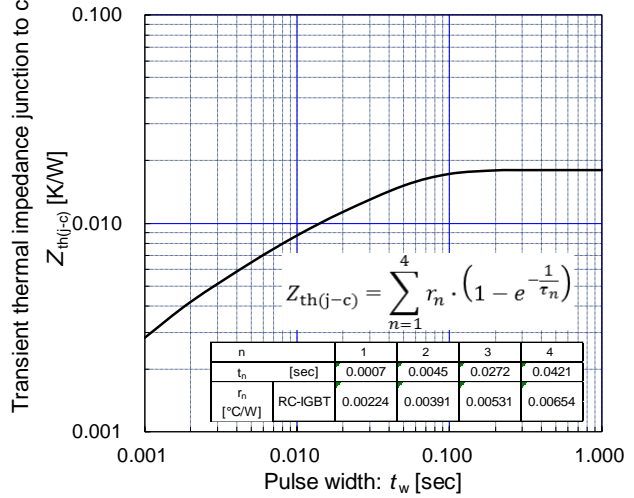
[Inverter]  
Forward recovery characteristics (typ.)



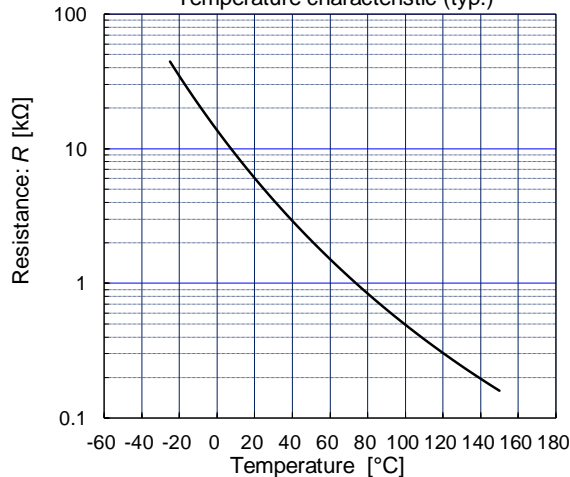
[Inverter]  
FWD safe operation area (typ.)  
 $T_{vj} = 175^\circ\text{C}$



[Inverter]  
Transient Thermal Resistance (max.)



[Thermistor]  
Temperature characteristic (typ.)





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**IGBT Modules**

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